

Cyclic Alkyl(amino) Carbene Stabilized Biradical of Disilicontetrachloride

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Supporting Information

ABSTRACT: One and a half decades ago the formation of Si₂Cl₄ from the intermediate species SiCl₂ was theoretically predicted to be exothermic. The hypothetical Si₂Cl₄ has never been experimentally synthesized and isolated. Herein, we report that the Si₂Cl₄ species was stabilized as singlet biradical (Cy-cAAC·)₂Si₂Cl₄ utilizing two cAAC (cyclic alkyl(amino) carbene). This compound is stable, isolable, and storable at rt under an inert atmosphere. The electronic structure and bonding were studied by theoretical calculations which revealed that the molecule possesses a singlet biradical ground state with an unpaired electron on each carbene C atom having opposite spin.

C ilicontetrachloride, disiliconhexachloride, acyclic, and cyclic Siliconperchlorides are well-known. They are chemical text book examples¹ and have received recognition for industrial applications.² However, to the best of our knowledge Si₂Cl₄ has never been published as a possible intermediate of $[SiCl_2]_x$ formation during the dechlorination process of SiCl₄.³ The dechlorination reaction is an important technical process, due to the formation of SiCl₄ as a side product during the reduction of HSiCl₃ to Si with hydrogen gas. It is well-known that in the presence of a base HSiCl₃ can produce dichlorosilylene which can be trapped as $(NHC)SiCl_2^{4a,b}$ by N-heterocyclic carbene (NHC). In the presence of triethylamine, Si₂Cl₆ produces SiCl₄ and Si₆Cl₁₄.^{4c} The exact mechanism is not known.^{4d} Hexachlorodisilane (Si₂Cl₆) undergoes disproportionation to produce SiCl₄ and SiCl₂ both of which were trapped by NHC too.^{4e} SiCl₂ could also be generated from Si₃Cl₈ in the presence of a tertiary amine.^{3d} None of the proposed mechanisms involves the formation of Si₂Cl₄. However, the theoretical calculation showed that the dissociation of Si₂Cl₄ into two SiCl₂ is endothermic by 17 kcal/mol.^{3c} This means the formation of Si₂Cl₄ from SiCl₂ is favorable. In 2003, Boganov et al. suggested that the dimerization of 2 SiCl₂ to Si₂Cl₄ is energetically favorable over complexation between SiCl₂ and molecular N₂.^{3e} This was concluded from the quantum chemical calculations and experimentally at low temperature by an argon-nitrogen matrix isolation of pyrolysis product (N₂-SiCl₂) from Si₂Cl₆. Two structures (trans-olefin and bridged structure; Scheme S1) of Si₂Cl₄ were theoretically

predicted. The calculated dimerization energy $(2 \operatorname{SiCl}_2 \rightarrow \operatorname{Si}_2\operatorname{Cl}_4)$ is -8.6 kcal mol⁻¹ for the *trans*-olefin structure and only -1.2 kcalmol⁻¹ for a bridged structure.^{3e} Gaseous SiCl₂ has been known for a long time, but it condenses to polymeric $(\operatorname{SiCl}_2)_n$. The stability and properties of the latter were investigated.^{3a,b,d,f} In 1998 the X-ray single crystal structures of a cyclic^{5a} and an acyclic^{5b} polymeric perchloropolysilane $(\operatorname{SiCl}_2)_n$ were reported by West et al. The generation of $\operatorname{SiCl}_2^{6a-c}$ and reactivity of Si₂Cl₆^{6d-i} have been studied. It is worth mentioning that the isolation and characterization of Si₂Cl₄ at rt are not achieved yet.

NHC can stabilize several low coordinate unstable intermediate species via strong σ -donation.^{4a,b} The above-mentioned (NHC)SiCl₂ was exclusively obtained from the reaction of HSiCl₂ with 2 equiv of NHC under the elimination of NHC·HCl (Scheme S2).^{4b} This means formation of (NHC)SiCl₂ from reaction of NHC and SiCl₂ (generated in situ). Alternatively, (NHC)SiCl₂ (B) was also prepared via the reduction of the adduct (NHC)SiCl₄ (A) with 2 equiv of KC₈ under the elimination of 2 equiv of KCl. Theoretical calculations on (NHC)SiCl₂ (B) showed that NHC forms a strong donor NHC \rightarrow Si σ -bond and the lone pair of electrons of NHCsilylenedichloride, (NHC)(Si(:)Cl₂), resides on the Si atom in the singlet ground state.^{4b} The lone pair of electrons on the Si atom of B can be even donated to the acceptor molecules.^{4e} Moreover, NHC and cAAC stabilized $(L)ECl_2$ (L = NHC, for E = Si, Ge, Sn; $^{2c,4b,7-8}$ L = cAAC for Ge, Sn) are known.⁹ Recently we published (NHC)SiCl₂^{4a,b} and two polymorphs of composition (cAAC·)₂SiCl₂^{10a} (cAAC = cyclic alkyl(amino) carbene). In view of the prominent role, which a Cl₂SiSiCl₂ molecule might play, we targeted the preparation of this unknown molecule. We utilized $(Cy-cAAC)SiCl_3$ (Cy-cAAC = $:C(CH_2)(CMe_2)(C_6H_{10})N-2,6-iPr_2C_6H_3)$ as a precursor instead of (NHC)SiCl₂, because treatment of the latter with cAAC resulted exclusively in the formation of $(cAAC \cdot)_2 SiCl_2$.^{10a,11}

NHC and cAAC are inherently different from each other since the HOMO–LUMO energy gap is smaller for the latter one. This can play a pivotal role for their unusual cAAC-silylene chemistry. NHC carbene provides strong σ -donation and acts as a weak π -acceptor due to the presence of two σ -withdrawing and

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 π -donating N atoms leading to a weaker bond strength between NHC and the Si atom when compared with that of cAAC.¹¹

When the cyclic alkyl(amino) carbene (cAAC) is used instead of the NHC:, one π -donating and σ -withdrawing N atom is replaced by one σ -donating quaternary C atom. Thus, the cAAC becomes a stronger σ -donor and π -acceptor when compared with that of NHC:.¹¹ Several radical species of main group elements such as $PN^{\bullet+}$, $P_2^{\bullet+}$, phosphinyl radical cation, $H-B^{\bullet+}$, CO⁺⁺, and ketene with biradical character were stabilized with cAAC:.¹² (Cy-cAAC)SiCl₄ (1) was reduced to the monoradical $(Cy-cAAC \cdot)SiCl_3(2)$ by 1 equiv of KC_8 .¹³ An NHC analogue of 2 is not known. The stronger π -acceptor property of Cy-cAAC is the reason why it stabilizes such radical species. Having (CycAAC·)SiCl₃ (2) in hand, it was intriguing to carry out the reduction of $(Cy-cAAC)SiCl_3$ (2) with another equivalent of KC_8 to obtain $(Cy-cAAC \cdot)_2 Si_2 Cl_4$ (3) (Scheme 1). Here, we report the synthesis, characterization, and theoretical calculations of the 1,4-biradical $(Cy-cAAC \cdot)_2 Si_2 Cl_4$ (3).



Compound $(Cy-cAAC \cdot)_2 Si_2 Cl_4$ (3) was synthesized by controlling the reaction temperature and the molar ratio of the precursor and reducing agent (Scheme 1). A 1:1 molar mixture of precursor (Cy-cAAC·)SiCl₃ (2) and KC₈ was cooled to $-105 \degree C$ using a frozen THF bath, and separately the solvent was also cooled to the same temperature. Both were mixed together via a cannula, and the resultant solution was stirred for 15 min at this temperature. Then the temperature was slowly raised to rt for another 30 min. In the mean time, a dark green solution of compound 3 was obtained (Scheme 1). The volume of the solvent was reduced and stored at -32 °C in a freezer to form dark green blocks of 3 in 85% yield. Alternatively compound 3 can also be prepared via the reduction of precursor (CycAAC)SiCl₄ (1) instead of 2 (Scheme 1) by 2 equiv of KC₈. This reduction should be carried out also at low temperature to exclusively obtain compound 3; otherwise, a mixture of several compounds (unreacted 1, 2, 3, and $(\mbox{Cy-cAAC})_2\mbox{Si}_2\mbox{Cl}_2)^{10,14}$ is produced. The reaction is very rapid when KC₈ is employed as a reducing agent, and hence temperature control is necessary. Compound 3 can be prepared within 1 h at a much higher temperature (0 °C) via the reduction of 1 by $Li^+(NiPr_2)^-$ in THF. After completion of the reaction the solvent was removed and product 3 was extracted with *n*-hexane. The concentrated

solution was stored at 0 $^{\circ}\mathrm{C}$ in a refrigerator to form big blocks of 3.

The solution of **3** is stable at -32 to 0 °C for \sim 3 months. The crystals of **3** are stable at rt for more than 4 months in an inert atmosphere. Compound **3** melts in the temperature range of 93–94 °C. The ²⁹Si NMR spectrum of **3** shows a resonance at 3.3 ppm which is downfield shifted when compared to the reported value $(-3.9 \text{ ppm})^{6b}$ for a polymeric perchloropolysilane $(SiCl_2)_n$. The UV–vis spectrum of **3** was recorded in THF which shows absorption bands at 222, 272, 305, 410, 552, 605 nm (see SI) while fluorescent yellow colored monoradical **2** (precursor) and related dark blue colored biradical (Cy-cAAC·)₂SiCl₂ absorb at 263, 304, 337, 405¹³ and 260, 308, 405, 582^{10b} nm, respectively.

Compound 3 crystallizes in space group $P\overline{1}$ with a center of symmetry located in between two Si atoms of the molecule. Both Si atoms adopt a distorted tetrahedral geometry. Each silicon atom is bound to one carbene carbon atom, two chlorines, and one silicon atom. The selected bond lengths and angles are given in the Figure 1 caption. The values are in good agreement with



Figure 1. Molecular structure of compound 3. H atoms are omitted for clarity. Selected experimental [calculated at the BP86/def2-SVP level for the ground state] bond lengths [Å] and angles [deg]. Si1–Si1' 2.454(3) [2.416], Si1–C1 1.846(5) [1.845], C1–N1 1.376(6) [1.379], Si1–Cl1 2.061(2) [2.085], Si1–Cl2 2.068(2) [2.099]; C2–C1–N1 109.5(4) [109.9], C2–C1–Si1 122.6(3) [124.2], N1–C1–Si1 123.9(3) [123.5], C1–Si1–Cl1 106.71(16) [107.5], C1–Si1–Cl2 109.63(16) [109.5], C1–Si1–Si1' 125.95(17) [124.3], Cl1–Si1–Cl2 102.43(9) [103.7], Cl1–Si1–Si1' 108.23(11) [108.1], Cl2–Si1–Si1' 101.52(10) [101.9].

those of the previously calculated values for a trans-olefin structure of the optimized discrete Si₂Cl₄ molecule (Scheme S1). The Si₂Cl₄ unit of 3 adopts a *trans*-olefin-like configuration, as predicted by Swihart et al.^{3c} and Boganov et al.^{3e} to be the most stable form. The Si–Si bond distance in 3 is 2.454(3) Å which is close to that of hypothetical Si₂Cl₄ (2.446 Å, Scheme S1).^{3e} Generally, the average Si-Si single bond distance is close to 2.35 Å.^{3,6,14} The Si–Si single bond distance of 2.424(8) Å^{5b} has been reported for polymeric perchloropolysilane $(SiCl_2)_n$. The C_{cAAC} -Si bond distance of 3 is 1.846(5) Å which is close to that found for precursor (Cy-cAAC·)SiCl₃ (2) (1.8193(8)) and biradical (Cy-cAAC·)₂SiCl₂ (1.854(2), 1.843(2) Å). The C_{cAAC}-N bond distance of 3 is 1.376(6) Å which is very close to that of the monoradical 2 $(138.27(10) \text{ Å})^{13}$ and slightly smaller than those of SiCl₂ bridged singlet biradical (Cy-cAAC·)₂SiCl₂ (1.400(2), 1.403(2) Å).^{10b} The carbenes of **3** are oriented in a trans-position with respect to the central Si₂Cl₄ unit with a C-Si-Si-C torsion angle of 180°. The carbene C atom adopts a near trigonal planar geometry with a sum of angles (356°) which is far from that of $(Me_2$ -cAAC-H)₂O (330.26°) (see SI of ref 9a)

but close to those of the monoradical **2** (357.33°) and the biradical (Cy-cAAC·)₂SiCl₂ (354.8° , 355.7°).^{10,13} In comparison the sum of the angles of free cAAC is 359.9° ,^{10b} suggesting a C–Si covalent electron-sharing single bond between the carbene C atom and the Si atom of **3**. The entire mentioned bond data suggest that **3** contains two unpaired electrons, one on each carbene C atom retaining the radical character like precursor **2**. Hence **3** can be considered as a Si₂Cl₄ bridged carbon centered 1,4-biradical.

We have performed DFT calculations to illustrate the electronic structure and bonding scenario of compound 3. Two possible bonding situations were previously shown for a similar type of compound $(Cy-cAAC \cdot)_2 SiCl_2$.^{10a} If the ligand CycAAC involves donor-acceptor type bonding to the SiCl₂ unit $(C \rightarrow Si)$ then the molecule will be a closed-shell singlet, whereas when a covalent bonding (C-Si) exists, the biradical state will be stabilized. We have optimized the geometry (taken from the crystal structure) at the M06-2X/SVP level of theory and found that the singlet electronic state is less stable than the triplet by 7.5 kcal mol⁻¹ (M06-2X/TZVP//M06-2X/SVP level). Further optimization of the geometry 3 using the broken symmetry formalism reveals that the biradical singlet state is 2.8 kcalmol⁻¹ lower in energy than the triplet state. The optimized geometrical parameters of the biradical singlet state of 3 exhibit a closer resemblance with the crystal structure than the closed-shell singlet and triplet electronic states (Table S4 and Figure S3). For further validation the CASSCF(2,2)/SVP method was employed for the optimization of geometry 3 in the singlet state. The coefficient values for the three singlet components are 0.80(2/0), -0.60(0/2), 0.0(1/1), and the diagonal elements of the final one electron symbolic density matrix are 1.3 and 0.7, respectively. These results indicate that the stable form of compound 3 contains two unpaired electrons with opposite sign. Similar results were also obtained from fragment analysis (Figure S4), where two Cy-cAAC ligands in the triplet state combine with two triplet SiCl₂ units resulting in the biradical species 3 (see Figure 2). Thus, 3 can be considered as a singlet 1,4-biradical.¹⁵ The



Figure 2. Computed Mulliken spin density plot (top, isosurface = 0.006 au) of 3 in (a) biradical singlet and (b) triplet state at the UM06-2X/TZVP//UM06-2X/SVP level of theory. Bonding orbitals (bottom) in fragments of compound 3.

unpaired electrons are stabilized by coupling with the neighboring lone pair of the N atoms in cAAC. In the singlet electronic state of the Si₂Cl₄ unit, the Si=Si bond is longer (2.424 Å) than a typical Si–Si bond (2.362 Å), a characteristic feature for a nonclassical double bond exhibiting trans-bent geometry resulting from $\sigma-\pi$ mixing.¹⁶ Surprisingly, in 3 the Si–Si bond distance is 2.416 Å although the SiCl₂ subunits

combining to form the Si₂Cl₄ fragment are in triplet states (Figure 2). This typical bonding scenario can be explained taking resort in the NBO analysis. Under bond formation of the free Si_2Cl_4 unit with two carbene ligands (L), the electron density on Si atoms is reduced ($\Delta q_{Si} = 0.402 e$) and successively the bond occupancy of Si-Si decreased by 0.073 e resulting in an elongated Si-Si bond (2.416 Å) with respect to the normal bond length (2.319 Å in Si_2Cl_6 molecule). The Mulliken spin density distribution plot of singlet biradical and triplet form entails that the two unpaired electrons are localized at the C(carbene) of the Cy-cAAC donor ligand (Figures 2 and S5). The radical intermediate $(Cy-cAAC \cdot)_2 Si(\cdot)Cl_2$ formed during the reaction depicted in Scheme 1 possesses a singlet ground state. Dimerization of two such species to form the 1,4-biradical 3 is favorable with an exothermicity of -30.9 kcal/mol ($\Delta G_{298} =$ -14.7 kcal/mol; Figure S4). To exemplify the role of interaction between the Si-Si bond and the carbon radical centers in stabilizing the biradical 3, we have optimized the structure with H atoms saturating the radical centers (3 2H; refer to Figure S6).¹⁵ Formation of such species from its monomers is stabilized by -70.1 kcal/mol, which is -3.3 kcal/mol less exothermic with respect to the formation of 3 from its monomeric triplet fragments. This indicates the stabilization influence, though less, with the σ bond and the radical centers.

Calculated Laplacian distribution $[\nabla^2 \rho(\mathbf{r})$, see computational details] of the C1–Si1–Si1' plane of 3 is shown in Figure 3



Figure 3. Contour plot of Laplacian distribution $[\nabla^2 \rho(r)]$ in the C1–Si1–Si1' plane of **3.** Solid lines indicate the areas of the charge concentration $(\nabla^2 \rho(r) < 0)$ while dotted lines mean the charge depletion $(\nabla^2 \rho(r) > 0)$. The range of contours of the Laplacian is -8×10^2 to $+8 \times 10^2$. Solid lines connecting atomic nuclei (black) are the bond paths, and those lines (purple) separating the atomic basins indicate the zero-flux surface crossing the molecular plane.

(N1-C1-Si1 plane in Figure S7). We have noticed the charge concentration of the lone pair at the C(carbene) (solid lines) and charge depletion at the silicon end (dotted lines). The C(carbene)–Si bonds are polarized toward the C atom. This type of bonding situation was also supported by the NBO results where the C(carbene) atom has contributed ~70% electron to the C(carbene)–Si bond.

In conclusion we have shown the hypothetical Si_2Cl_4 can be stabilized by two cyclic alkyl(amino) carbenes with a general formula of $(Cy-cAAC \cdot)_2Si_2Cl_4$ (3). $(Cy-cAAC)SiCl_4$ (1) or $(Cy-cAAC \cdot)SiCl_3$ (2) was utilized as a precursor. The reduction of 1 or 2 was carried out in THF at low temperature with calculated equivalents of KC₈ (Scheme 1). The crystals of 3 are dark green in color and stable at rt in an inert atmosphere. 3 melts in the temperature range 93–94 °C. Organic linker bridged TEMPOor nitroxide-based biradicals are studied.¹⁷ However, a Si_2Cl_4 bridged 1,4-biradical such as 3 is an unprecedented species. Theoretical calculations were performed to study the electronic structure and the bonding of **3** which revealed that **3** possesses a singlet 1,4-biradical spin ground state with an unpaired electron on each carbene C atom having opposite spin. Calculations employing broken symmetry formalism revealed that the biradical singlet state of **3** is 2.8 kcal mol⁻¹ lower in energy than the triplet state. **3** adopts a *trans*-olefin configuration (Figure 1) similar to what was previously predicted for the hypothetical Si₂Cl₄ molecule (Scheme S1) formed via favorable dimerization of SiCl₂.

ASSOCIATED CONTENT

S Supporting Information

Syntheses of **3**, UV–vis, crystal structure determination, and theoretical details. This material is available free of charge via the Internet at http://pubs.acs.org.

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Notes

The authors declare no competing financial interest.

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